A110a0

Unitized Semiconductor Devices - Page 1 of 1



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Nelsure Material:         Metal         Overall Lenght:         2.00 Inches         Terminal Lenght:         0.300 Inches         Overall Diamote::         0.370 Inches         Data Electronic Davice Engineering Council/Jedec/ase Outline Designation:         7.77         Corponent Name And Quantity:         2 Tarrial         Doming Method:         Tarrial         Terminal         Terminal Cole Diameter:         0.200 Inches         Partners Rovided:         Battores Rovided:         1000 Interscret         0.2010 Indexer         2.2020 Inches         Partners Rovided:         1000 Interscret         2.2030 Inches         2.2040 Inches         2.2050 Inches         2.0500 Inches <th>View Online at https://a</th> <th>aerobasegroup.com/nsn/5961-01-177-1335</th>	View Online at https://a	aerobasegroup.com/nsn/5961-01-177-1335
Careal Length:         Caseo Inches         Terminal Length:         Casoo Inches         Oxaral Diameter:         Casoo Inches         Diart Electronic Device Engineering Council/jedec/case Outline Designation:         To-77         Component Name And Quantity:         2 transistor         Mounting Method:         Terminal         Terminal Circle Diameter:         Casoo Inches         Patters Forvided:         Patters Forvided:         Patters Forvided:         Solicon all transistor         Outling Method:         Caroo Material:         Solicon all transistor         Voltage Rating In Volts Per Characteristic:         Caroo Mulliamperes source outoff current all transistor and 12.0 breakdown voltage, collector-to-base, envilter open all transistor and 12.0 breakdown voltage, collector-to-base, envilter open all transistor         Outor Millamperes source outoff current all transistor         Power Rating Per Characteristic:         20.0 millamperes source outoff current all transistor         Power Rating Per Characteristic:         20.0 millamperes outor outor open engine drawing, such as a contractor drawing, original equipment manufacturer drawing engine equipment manufacturer drawing engine equipment manufacturer drawing engine equipment manufacturer drawing engine equipment manufactur	Inclosure Material:	
0.200 indes  Social Lengti:  Logo indes  Social District Exprise Expri	Metal	
Terminal Length:         0.500 inches         Overall Diameter:         0.370 inches         Johnt Electronic Device Engineering Council/Jede/case Outline Designation:         Ter.77         Component Name And Quantity:         2 transistor         Terminal         Terminal         Terminal         2 200 inches         Soution Buster:         0.200 inches         Features Provided:         Hermetically sealed case         Somiconductor Material:         200 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor         Voltage Rating In Volts Per Characteristic:         20.00 breakdown voltage, collector-to-base, collector open all transistor         Current Rating Per Characteristic:         20.00 millivatts small-signal input power, common-collector absolute all transistor         Power Rating Tempurature Per Measurement Point:         200.0 degress celsius junction         Soutionallivatts small-signal input power, common-collector absolute all transistor         Soutionallivatts small-signal input power, common-collector absolute all transistor         Soution:       Soution:         Soution:       Soution:         Souto derives celsius junction	Overall Length:	
0.500 inches Overall Diameter: 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-77 Component Name And Quantity: 2 transistor Mounting Mothod: Terminal Terminal Terminal Crele Diameter: 0.200 inches Features Provided: Hermetically sealed case Semiconductor Material: Silicon all transistor Vottage Rating In Votts Per Characteristic: 20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor Vottage Rating In Votts Per Characteristic: 20.0 breakdown voltage, collector-to-base, emitter open all transistor Current Rating Per Characteristic: 20.0 millimentes source cutoff current all transistor Power Rating Per Characteristic: 20.00 millimentes source cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esource cutoff current all transistor Power Rating Per Characteristic: 20.00 degrees esolusi junction Power Rating Per Characteri	0.260 inches	
Overall Diameter:       0.370 inches         Join Electronic Device Engineering Council/jedec/case Outline Designation:       1         To-77       Component Name And Quantity:         2 transistor       Mounting Method:         Terminal       Terminal Cicle Diameter:         0.200 inches       Peatronic Name And Quantity:         0.200 inches       Second Cicle Diameter:         0.200 inches       Peatronic Name And Cicle Diameter:         0.200 inches       Semiconductor Material:         Somiconductor Material:       Second Cicle Diameter:         0.200 inches       Peatronic Name And Quantity:         Somiconductor Material:       Second Cicle Diameter:         0.200 inches       Peatronic Name And Cicle Diameter:         0.200 inches       Cicle Diameter: Second Cicle Circle Design and Taxistor and T2.0 breakdown voltage, collector-to-emitter, base open all transistor and T2.0 breakdown voltage, collector-to-emitter, base open all transistor and A.5 breakdown voltage, collector-to-base, collector open all transistor         Current Rating Per Characteristic:       Socio Miliamperes source cutoff current all transistor         Maximum Operating Tempurature Per Measurement Point:       Socio All Second Cicle Cicl	Terminal Length:	
0.370 indeks         Joint Electronic Device Engineering Council/jedec/case Outline Designation:         To-77         Component Name And Quantity:         2 transistor         Mounting Method:         Terminal         Terminal Circle Diameter:         0.200 inches         Features Provided:         Hermetically sealed case         Semiconductor Material:         Silicon all transistor         Voltage Rating In Volts Per Characteristic:         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor         Power Rating Per Characteristic:         20.0 on miliwaits small-signal input power, common-collector absolute all transistor         Power Rating Per Characteristic:         20.0 on gorgene selsius junction         Special Features:         20.0 onglivaits small-signal input power, common-collector absolute all transistor         Maximum Operating Tempurature Per Measurement Point:         20.0 onglivaits small-signal input power, common-collector absolute all transistor governing drawing.         Power Rating Per Characteristic:         20.0 breakdown wight (his is the basic governing drawing, such as a contractor drawing, original equipment manufacture drawing etc; excludes any specification, standard or other document that may be referenced in a basic governing drawing: <td>0.500 inches</td> <td></td>	0.500 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:         To-77         Compornt Name And Quantiy:         2 transistor         Mounting Method:         Terminal         Terminal Orche Diameter:         0.200 inches         Feurnes Provided:         Hermetically sealed case         Semiconductor Material:         20.10 inches         Outling In Volts Per Characteristic:         20.10 break down voltage, collector-to-base, entiter open all transistor and 12.0 break down voltage, collector-to-entiter, base open all         20.10 break down voltage, collector-to-base, entiter open all transistor         20.10 break down voltage, collector-to-base, entiter open all transistor         20.10 break down voltage, collector-to-base, entiter open all transistor         20.10 break down voltage, entiter-to-base, collector open all transistor         20.10 break down voltage, entiter-to-base, collector open all transistor         20.10 break down voltage, entiter-to-base, collector open all transistor         20.10 break down voltage, entiter-to-base, collector open all transistor         20.10 break down voltage, entiter-to-base, collector open all transistor         20.10 break down voltage, entiter open ell transistor         20.10 dilatitatitatis mali-signal input power, common-collector absolute all transistor         20.10 dilatitatis mali-signal in	Overall Diameter:	
To-77 Component Name And Quantity: 2 transistor Mounting Method: Terminal T	0.370 inches	
Component Name And Quantity:       2         2 transistor       4         Houring Method:       5         Terminal       5         Cozo Inches       5         Fatures Provided:       5         Hermelically sealed case       5         Semiconductor Material:       5         Silcon all transistor       7         Voltage Rating In Volts Per Characteristic:       7         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-base, collector open all transistor         Current Rating Per Characteristic:       7         20.0 onliniwatts small-signal input power, common-collector absolute all transistor       7         Power Rating Per Characteristic:       7         20.0 onliniwatts small-signal input power, common-collector absolute all transistor       7         Power Rating Per Characteristic:       7         20.0 digrees celsius junction       7         Power Rating Per Characteristic:       7         20.1 digrees transistor incomponent: rapn       7         Power Rating Per Characteristic:       7         20.1 digrees celsius junction       7         Power Rating Per Characteristic:       7         20.1 digrees celsius junction       7 <td< td=""><td>Joint Electronic Devic</td><td>ce Engineering Council/jedec/case Outline Designation:</td></td<>	Joint Electronic Devic	ce Engineering Council/jedec/case Outline Designation:
2 transistor Automing Method: Forminal Forminal Forminal Forminal Core blameter: O.200 inches Features Provided: Hermetically sealed case Semiconductor Material: Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor Current Rating Per Characteristic: 50.00 milliamperes source cutoff current all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor Current Rating Per Characteristic: 50.00 milliamperes source cutoff current all transistor Power Rating Per Characteristic: 40.00 milliamperes source cutoff current all transistor Power Rating Per Characteristic: 50.00 comilliamperes source cutoff current all transistor Power Rating Per Characteristic: 50.00 comilliamperes source cutoff current all transistor Power Rating Per Characteristic: 50.00 comilliamperes source cutoff current all transistor Power Rating Per Characteristic: 50.00 comilliamperes source cutoff current all transistor Power Rating Per Characteristic: 50.00 comilliamperes source cutoff current all transistor Power Rating Per Characteristic: 50.00 drawing (his is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing etc: excludes any specification, standard or other document that may be referenced in a basic governing drawing current Tipe And Quantity: 6 unisulated wire lead Shell Life: Na Characteristic: 7 Current Reasurement Point: 7 Current Reasurement Point: 7 Current Reasurement Point: 7 Current Reasurement: 7 Current Re	To-77	
Noutling Method:       Terminal         Terminal Circle Diameter:       Outling         0.200 incles       Terminal Circle Diameter:         Features Provide:       Terminal Circle Diameter:         Semiconductor Material:       Terminal Circle Diameter:         Solition all transistor       Semiconductor Material:         Solition all transistor       Solition all transistor         Voltage Rating In Volts Per Characteristic:       Terminal Per Characteristic:         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor         Power Rating Per Characteristic:       Power Rating Per Characteristic:         0.00 milliamperes source cutoff current all transistor       Power Rating Per Characteristic:         0.00 digrees celsius junction       Soliticat Paterueres:         0.00 digrees celsius junction       Soliticat Paterueres:         0.00 digrees celsius junction patern arrangement: npn       Soliticat Paterues:         0.00 distication, standard or other document that may be referenced in a basic governing drawing:       Current all transistor governing drawing, such as a contractor drawing, original equipment manufacturer drawing:         Solitististististististististististististis	Component Name An	d Quantity:
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Terminal Circle Diameter:         0.200 inches         Features Provided:         Hermetically sealed case         Semiconductor Material:         Silicon all transistor         Voltage Rating In Volts Per Characteristic:         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor         Current Rating Per Characteristic:         20.0 millimaperes source cutoff current all transistor         Power Rating Per Characteristic:         20.0.0 milliwatts small-signal input power, common-collector absolute all transistor         Maximum Operating Tempurature Per Measurement Point:         20.0.0 degrees celsius junction         Special Features:         All transistor junction pattern arrangement: npn         Test Data Document:         20.0 millianguade wire lead         Sheft Life:         Via         Uni Of Measure:         Via         Via         Uni Of Measure:            Pointilarization:         No	Mounting Method:	
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Features Provided:         Hermetically sealed case         Semiconductor Material:         Silicon all transistor         Voltage Rating In Volts Per Characteristic:         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor         Outer Rating Per Characteristic:       0.0 milliamperes source cutoff current all transistor         Power Rating Per Characteristic:       0.0 milliwatts small-signal input power, common-collector absolute all transistor         Maximum Operating Tempurature Per Measurement Point:       200.0 degrees celsius junction         Special Features:       200.1 degrees celsius junction         Suboon-151-0139-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing)         torimal Type And Quantity:       200         to unisulated wire lead       200         Shel Lide:       200         Via Cime	Terminal Circle Diamo	eter:
Hermetically sealed case         Semiconductor Material:         Silicon all transistor         Voltage Rating In Volts Per Characteristic:         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor         Current Rating Per Characteristic:         30.0 on milliamperes source cutoff current all transistor         Power Rating Per Characteristic:         400.0 milliamity small-signal input power, common-collector absolute all transistor         Maximum Operating Tempurature Per Measurement Point:         200.0 degrees celsius junction         Special Features:         All transistor junction pattern arrangement: npn         Test Data Document:         80009-151-0139-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing)         etc: scludes any specification, standard or other document that may be referenced in a basic governing drawing)         to insulated wire lead         Shelf Life:         Na         Unt Of Measure:         -         -         Pointlarization:         Na	0.200 inches	
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Voltage Rating In Volts Per Characteristic:         20.0 breakdown voltage, collector-to-base, emitter open all transistor and 12.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 breakdown voltage, emitter-to-base, collector open all transistor         Current Rating Per Characteristic:         50.00 milliamperes source cutoff current all transistor         Power Rating Per Characteristic:         400.0 milliwatts small-signal input power, common-collector absolute all transistor         Maximum Operating Tempurature Per Measurement Point:         200.0 degrees celsius junction         Special Features:         All transistor junction pattern arrangement: npn         Test Data Document:         80009-151-0139-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)         Terminal Type And Quantity:         6 uninsulated wire lead         Sheft Life:         N/a         Unit Of Measure:            Demilitarization:         No	Semiconductor Mater	rial:
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Power Rating Per Characteristic:         400.0 milliwatts small-signal input power, common-collector absolute all transistor         Maximum Operating Tempurature Per Measurement Point:         200.0 degrees celsius junction         Special Features:         All transistor junction pattern arrangement: npn         Test Data Document:         80009-151-0139-00 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing)         etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)         Terminal Type And Quantity:         6 uninsulated wire lead         Shelf Life:         N/a         Unit Of Measure:         -         -         Demilitarization:         No	Current Rating Per Cl	haracteristic:
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